Review of Vertex/Silicon detector Technology

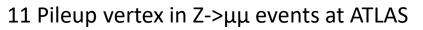
Zhijun Liang Institute of High Energy Physics, CAS

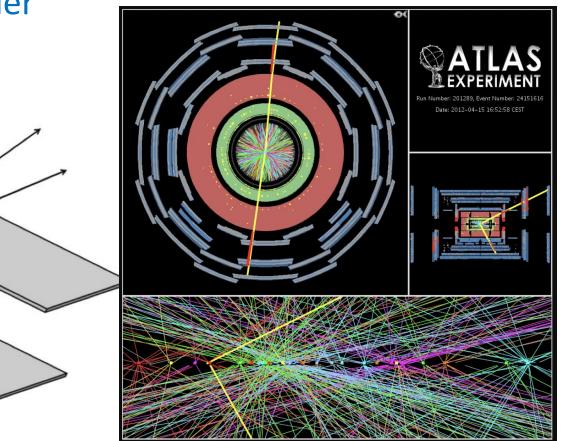
OUTLINE

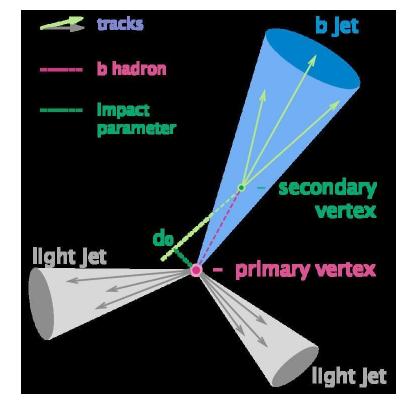
- Overview of vertex detector
- CEPC vertex detector R & D
- More Future prospect

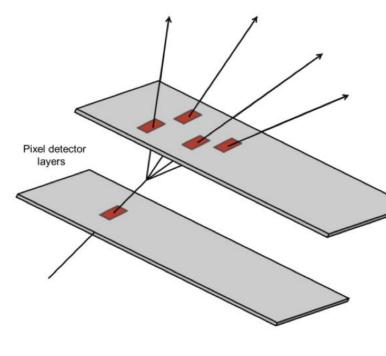
WHY WE NEED VERTEX DETECTOR ?

- High precision vertex detector essential
 - Flavor physics
 - Higgs physics (H \rightarrow bb/cc/gg and H \rightarrow tt)
 - Pileup vertex rejection for hadron collider





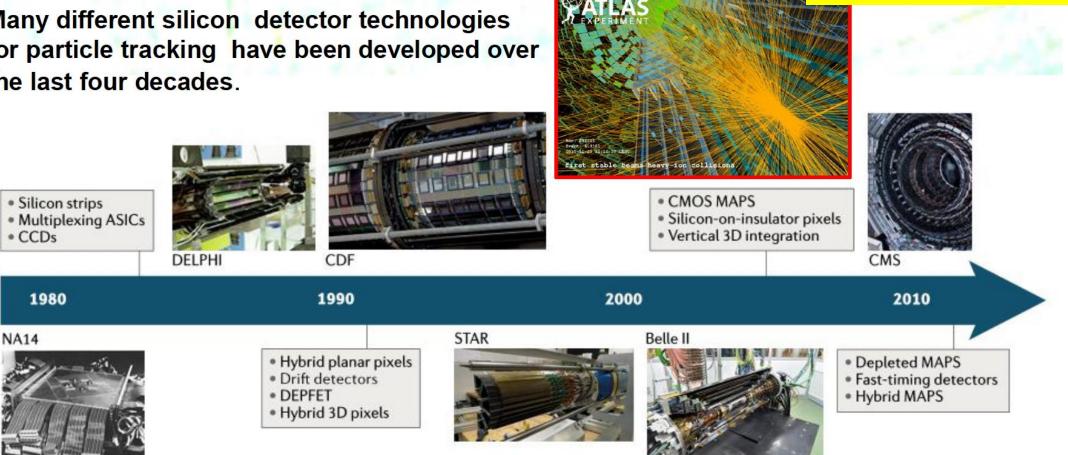




SILICON DETECTOR DEVELOPMENT

Many different silicon detector technologies for particle tracking have been developed over the last four decades.

P.Allport, CERN detector seminar, https://indico.cern.ch/event/960851 **CERN, Oct.8 2020**



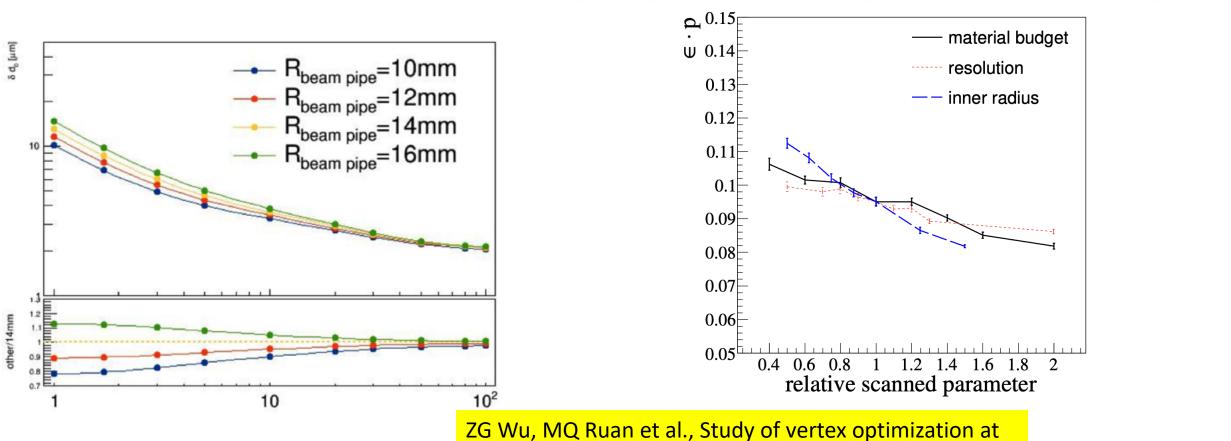
Applications of silicon strip and pixel-based particle tracking detectors - Nature Reviews Physics - https://doi.org/10.1038/s42254-019-0081-z Allport2019ER

What is remarkable is that every decade the instrumented areas have increased by a factor of 10 while the numbers of channels in the largest arrays have increased by a factor of 100.

VERTEX DETECTOR FOR FUTURE COLLIDER: GENERAL WISHLIST

- Wishlist for vertex detector
 - Closer to beam pipe (most important!)
 - Minimum material





the CEPC, 2018 JINST 13 T09002

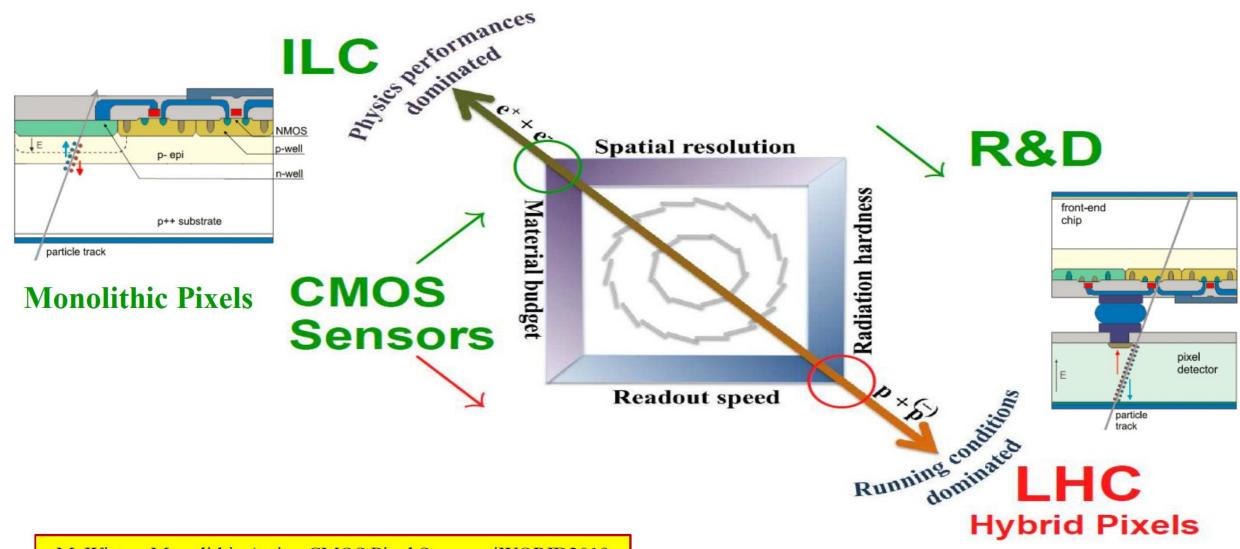
 $\epsilon \cdot p = 0.095(1 - 0.14 \frac{\Delta x_{\text{material}}}{1 - 0.09})(1 - 0.09 \frac{\Delta x_{\text{resolution}}}{1 - 0.23})(1 - 0.23 \frac{\Delta x_{\text{radius}}}{1 - 0.23})$

*x*_{material}

 $x_{\rm resolution}$

 $x_{\rm radius}$

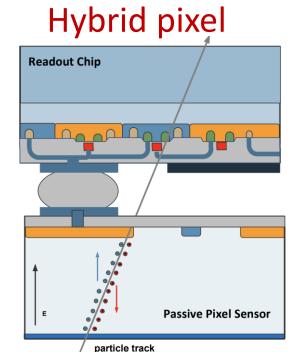
SILICON DETECTOR DEVELOPMENT



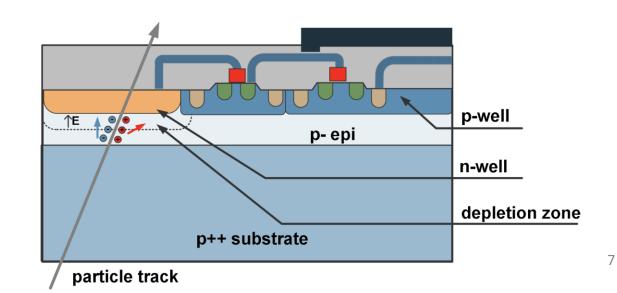
M. Winter, Monolithic Active CMOS Pixel Sensors, iWORID2019

VERTEX SENSOR DEVELOPMENT

- Hybrid pixel technology (example: ATLAS and CMS, LHCb)
 - Sensor and ASIC are designed separately, integrated by bump bonding
 - Advantage: Radiation hard, advanced in spin off application (Timepix, ...)
 - Drawback: material budget (sensors and ASIC are both about 300um thick)
- Monolithic pixel (example: Star, BELLE2, ALICE ITS2, Mu3e....)
 - Advantage: low material budget (can be thin down to $50\mu m$)
 - Drawback: radiation hardness is not as good compared to hybrid pixel sensor



Monolithic Pixels

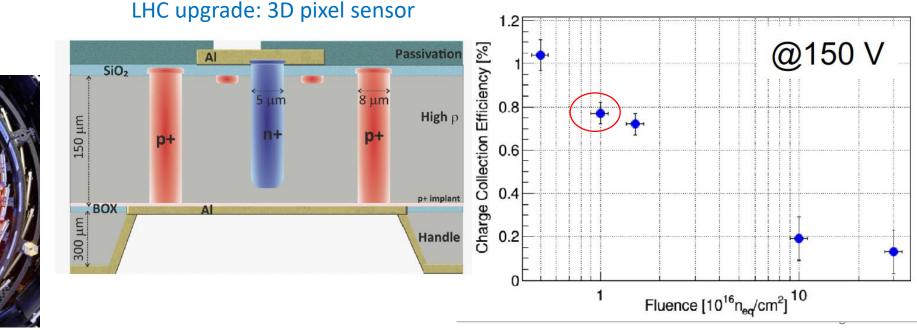


Hybrid pixel technology

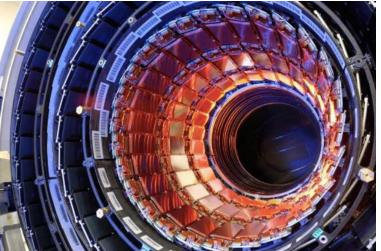
Radiation sensor

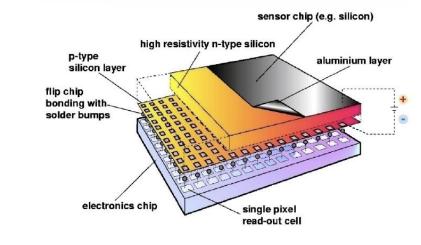
• Fast ASIC

- Current LHC operation showed pixel can work @ 10¹⁵ Neq/cm2 fluence
- LHC upgrade (3D pixel sensor) \rightarrow work up to $2*10^{16} N_{eq}/cm^2$ fluence
- Future Fcc-hh or Sppc: how to suffer $10^{17} N_{eq}/cm^2$ fluence ?
- RD53 chip: fast readout chip for HL-LHC ATLAS and CMS vertex detectors
 3D pixel sensor performance M. Manna et al., NIMA 979(2020) 164458

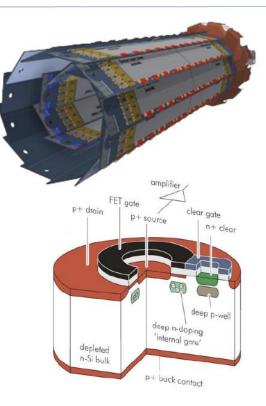


Current LHC: CMS silicon tracker





Monolithic sensors in HEP

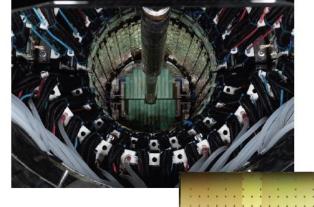


DEPFET in Belle



MIMOSA28 (ULTIMATE) in STAR IPHC Strasbourg First MAPS system in HEP Twin well 0.35 μm CMOS

- Integration time 190 μs
- No reverse bias -> NIEL few 10¹² 1 MeV n_{eq}/cm²
- Rolling shutter readout



ALPIDE in ALICEFirst MAPS in HEP with sparse

readout similar to hybrid sensors Quadruple well 0.18 μm CMOS

- Integration time <10 μs</p>
- Reverse bias but no full depletion
 -> NIEL ~10¹⁴ 1 MeV n_{eq}/cm²

W. Snoeys, CEPC workshop 2022

DEPLETED MAPS for better time resolution and radiation tolerance Large collection electrode LF Monopix, MuPix,... Extreme radiation tolerance and timing uniformity, but large capacitance Small collection electrode ARCADIA LF, TJ Malta, TJ Monopix, Fastpix, CLICTD, ... Sub-ns timing

- NIFI >10¹⁵ 1 MeV n
- NIEL >10¹⁵ 1 MeV n_{eq}/cm² and beyond

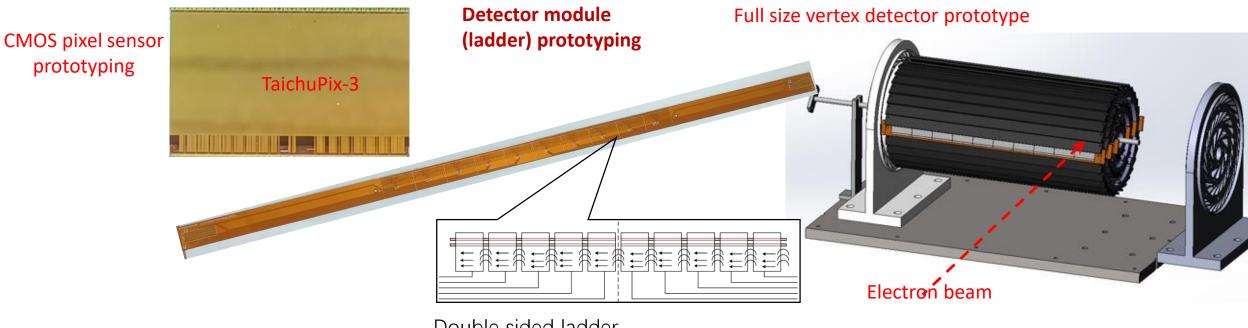
OUTLINE

- Overview of vertex detector
- CEPC vertex detector R & D
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Overview of CEPC vertex detector prototyping

• Vertex prototype R & D

- ➤CMOS Pixel Sensor chip R&D
- Detector module prototyping
- Detector assembly



Double sided ladder 10 sensors/ladder side, read out from both ends

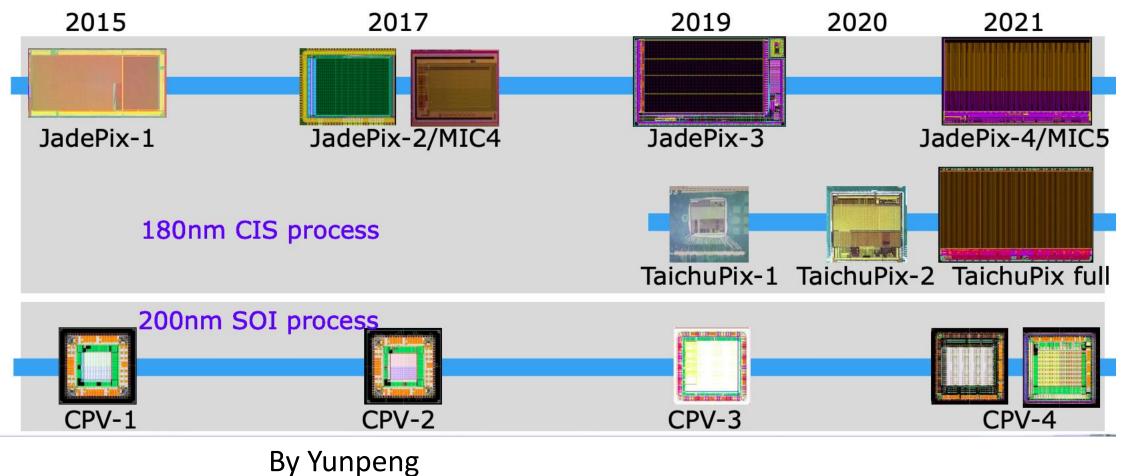
CMOS MONOLITHIC PIXEL SENSOR

- The existing CMOS monolithic pixel sensors can't fully satisfy the requirement
- Major constraints for the CMOS sensor
 - Pixel size: Single point resolution < 3 μ m
 - <500ns deadtime @40MHz clock at Z pole
 - Radiation tolerance (per year): 1 MRad &2×10¹² 1 MeV n_{eq}/cm²

experiment	Chip	Resolution	Readout Speed	TID
ALICE	ALPIDE	\checkmark	X	X (?)
ATLAS	Malta Monopix ATLASpix	Χ	✓	✓
Star	MIMOSA	\checkmark	Χ	X (?)

CEPC VERTEX SENSOR R & D

- CEPC Vertex detector sensor R & D timeline
 - Monolithic Pixel sensor design
 - Based on Tower Jazz CIS 180nm process (Jadepix , TaichuPix)
 - Based SOI 200nm process (CPV chip)

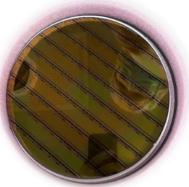


Large-scale MAPS sensor for CEPC: TaichuPix-3

• 6 TaichuPix-3 wafers (thinned down to 150 μm and diced)

Chip size: 26 ×16 mm Pixel size: $25\mu m \times 25\mu m$

15.9 mm

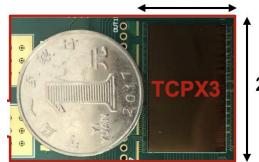




Wafer after thinning and dicing



Thickness after thinning

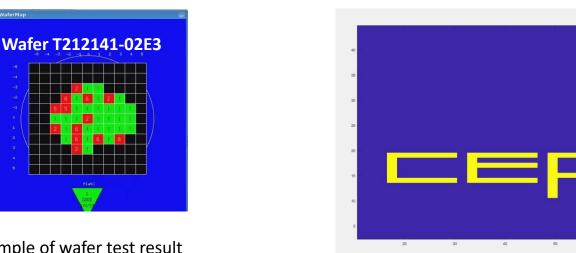


TaichuPix-3 chip vs. coin

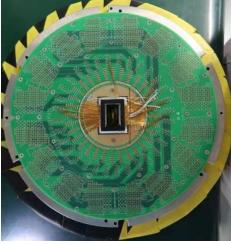
25.7 mm

8-inch wafer

wafer test on probe-station \rightarrow 70-80% yield



Functional tests of the chip

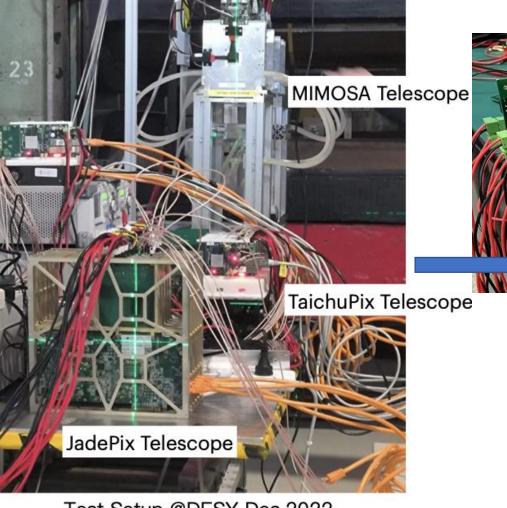


Probe card for wafer test

An example of wafer test result

CEPC vertex detector : DESY Testbeam

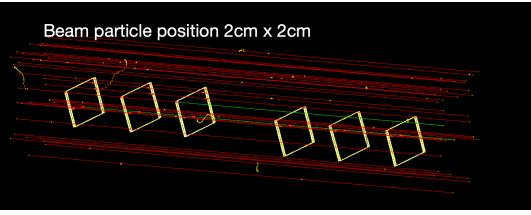
- The 6-layer of TaichuPix3 telescope
- 4-layer JadePix telescope.



Test Setup @DESY Dec.2022



Event display



512

384

256 -

128

0 -

0

256

768

1024

Hit maps

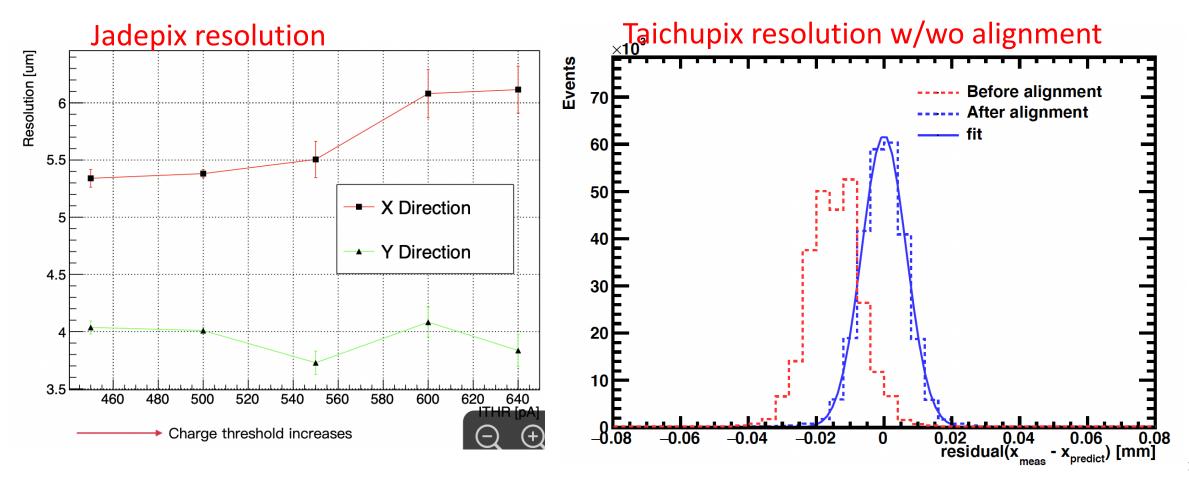
Board_02

512

col

CEPC vertex detector : DESY Testbeam

- Both CEPC pixel sensor prototype(Taichu and Jadepix) reach 3~5μm resolution
- Efficiency can reach ~ 99%
 - ➤ Taichu can work at 20Mhz clock with high efficiency.



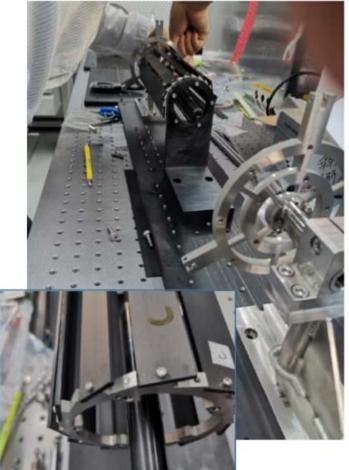
Vertex detector prototype assembly

• Installation procedure of 3 double layer of vertex detector





Middle barrel (half number of ladders)



Outer barrel (half number of ladders)



CEPC vertex detector: Ladder loading

- Loading procedure of ladder on vertex detector has been tested
- Another testbeam with full prototype expected in April 2023.

Wire-bonding

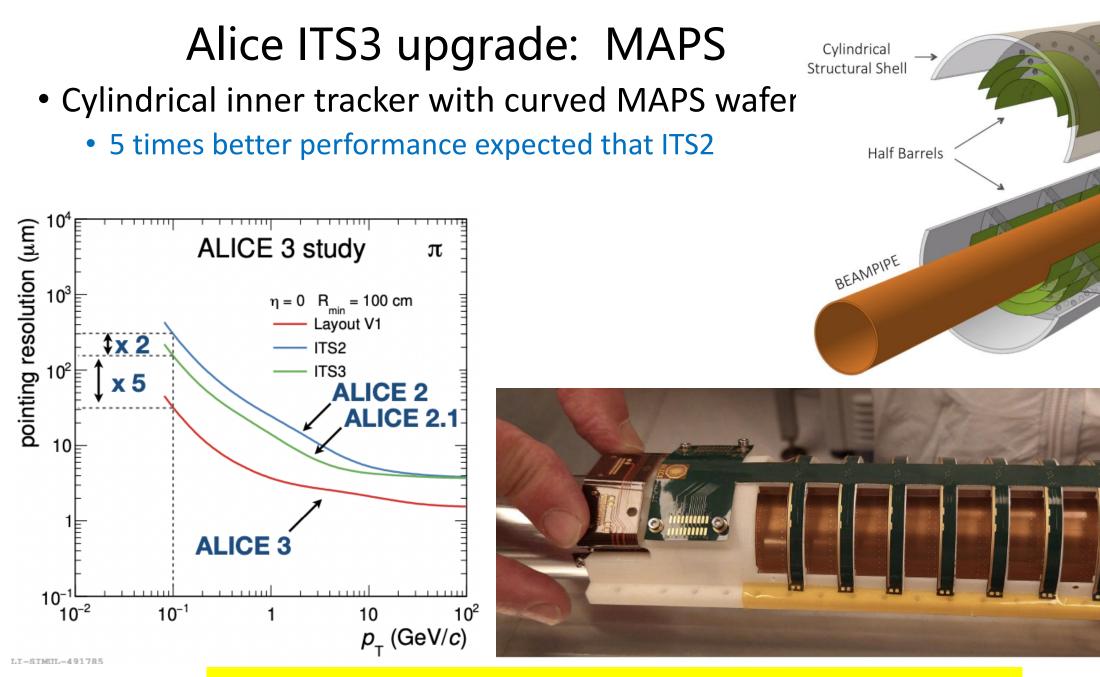






OUTLINE

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- CEPC vertex detector R & D
- More Future prospect
 - Alice upgrade
 - Timing detector



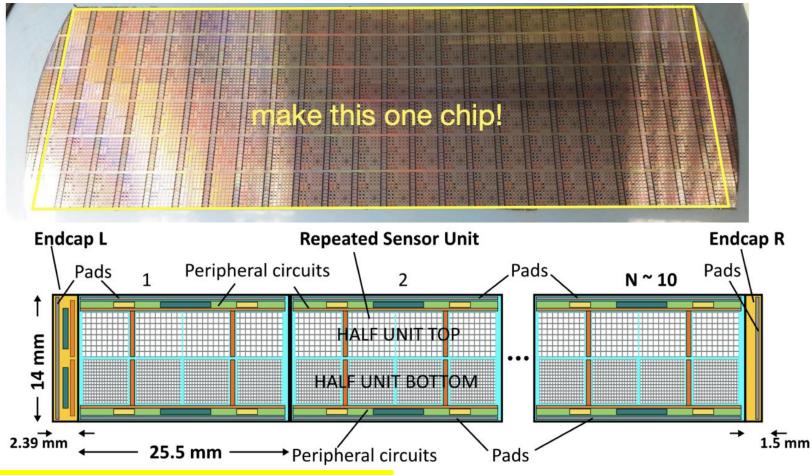
From Magnus Mager & Nicolò Jacazio (Alice collobration), ICHEP2022

Quarter-Laver

Alice ITS3 upgrade: 65nm technology & Stitching

- First submission of TPSCo 65 nm CMOS Imaging Technology successful
- next submission by Alice ITS3 community focus on stitching

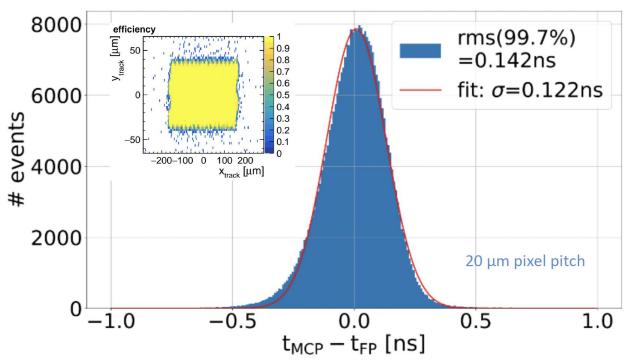


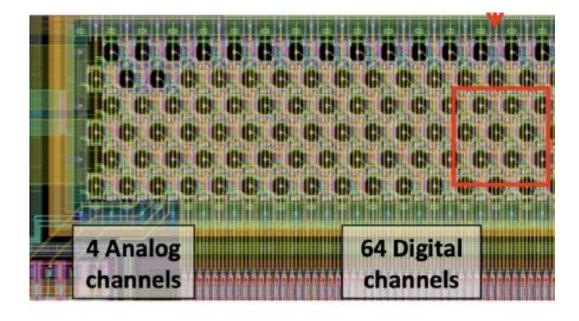


From Magnus Mager (Alice collobration), ICHEP2022

FastPix development

- Future vertex with 4D precision: space resolution + timing
 - \bullet 8.6, 10, 15 and 20 μm pixel pitch
 - Time resolution better than 150 ps at full efficiency
 - Si-Ge fast readout





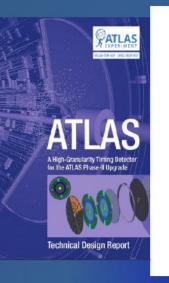
https://www.mdpi.com/2410-390X/6/1/13

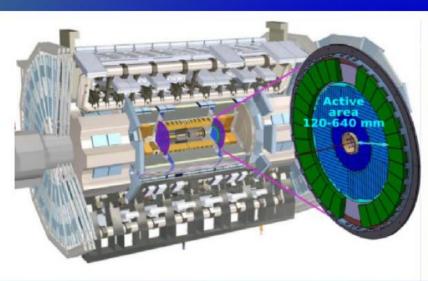
J. Braach, E. Buschmann, D. Dannheim, K. Dort, T. Kugathasan, M. Munker, M. Vicente

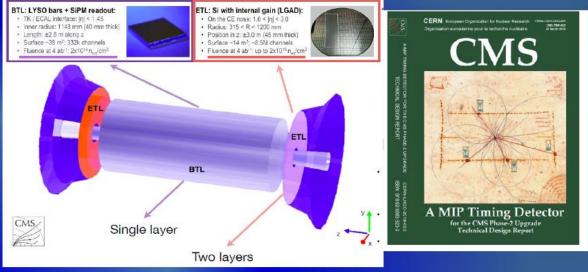
Silicon timing detector development

- Both ATLAS and CMS is aiming for silicon timing detector
 - with Low Gain Avalanche Detectors
 - 1.3mm² pad, with 30-50 ps resolution for single charge particle
 - Mainly for pileup vertex rejection
 - Also useful for search long-live particles search

ATLAS High Granularity Timing Detector:CMS Endcap Timing Detectors:Equipped with LGADs (1.3 x 1.3 mm² pads) targetting > 50 ps resolution (rad-hard only viable solution)

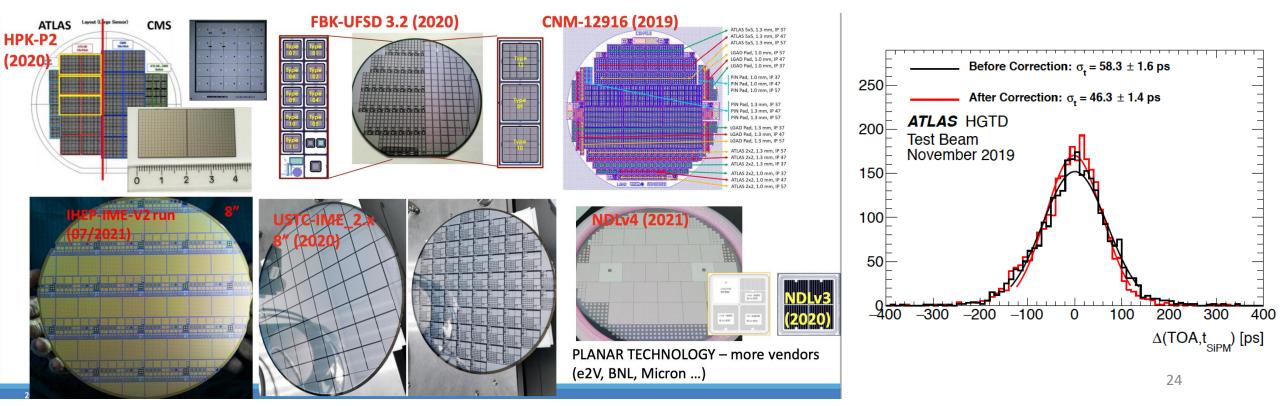






Silicon timing detector development

- Both ATLAS and CMS is aiming for silicon timing detector
 - with Low Gain Avalanche Detectors (LGAD)
 - 30-50 ps resolution for single charge particle
 - Lots of foundries are doing R & D for LGAD around the world
 - LGAD based 4D silicon tracker proposed for future EIC



Summary

- CMOS Monolithic pixel is very promising for future lepton collider
 - CPEC MAPS based vertex prototype is in good progress
 - 3 double layer prototype will be built and tested this year
 - ALICE ITS3 Cylindrical tracker has excellent potential in future colliders
- Fast time (<150ps time resolution) 4D pixel detector becoming feasible
 - LGAD based fast sensor
 - MAPS based technology